

INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Complete if Known			
		Application Number			
		Filing Date	Concurrently Herewith		
		First Named Inventor	Dharmesh Jawarani		
		Group Art Unit			
		Examiner Name			
Sheet		of		Attorney Docket Number	SC13056TP

U. S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
MG	AA	6,010,952	01/04/2000	Tsai <i>et al.</i>	
MG	AB	6,048,784	04/11/2000	Hong <i>et al.</i>	
MG	AC	6,255,214 B1	07/03/2001	Wieczorek <i>et al.</i>	
MG	AD	6,274,447 B1	08/14/2001	Takasou	
MG	AE	6,429,455 B1	08/06/2002	McNeil <i>et al.</i>	
MG	AF	6,465,335 B1	10/15/2002	Kunikiyo	

FOREIGN PATENT DOCUMENTS						
Examine r Initials*	Cite No. ¹	Foreign Patent Document Country Code ³ Number ⁴ Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
MG	AG	GB 2 214 708 A	09/06/1989	Bos-Cliteur <i>et al.</i>		
MG	AH	WO 00/36634	06/22/2000	Bai <i>et al.</i>		

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
MC	AI	Kittl <i>et al.</i> , "A Ti Salicide Process for 0.10 μ m Gate Length CMOS Technology," <i>Symposium on VLSI Technology Digest of Technical Papers</i> , 1996, pp. 14-15.	

Examiner Signature	<i>Myra Guerrero</i>	Date Considered	8-27-04
--------------------	----------------------	-----------------	---------

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English Language Translation is attached.

If you need assistance in completing the form, call 1-800-PTO-9199 (1-800-786-9199) and select option 2.